

## 74LVTN16245B

3.3 V 16-bit transceiver; 3-state Rev. 8 — 8 July 2024

### 1. General description

The 74LVTN16245B is a high-performance BiCMOS product designed for V<sub>CC</sub> operation at 3.3 V.

This device is a 16-bit transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an output enable input ( $n\overline{OE}$ ) for easy cascading and a direction input (nDIR) for direction control.

### 2. Features and benefits

- 16-bit bus interface
- 3-state buffers
- Output capability: +64 mA and -32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Power-up 3-state
- Live insertion and extraction permitted
- No bus current loading when output is tied to 5 V bus
- Latch-up protection
  - JESD78B Class II exceeds 500 mA
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C

### 3. Ordering information

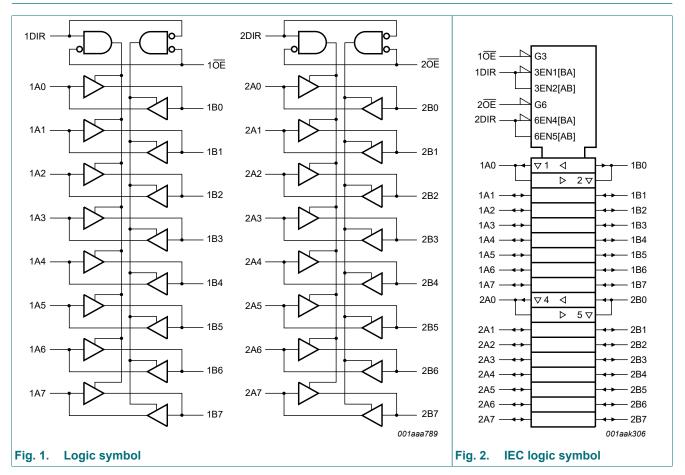
#### Table 1. Ordering information

| Type number     | Package           | Package |   |                 |  |  |
|-----------------|-------------------|---------|---|-----------------|--|--|
|                 | Temperature range | Name    | Description   | Version         |  |  |
| 74LVTN16245BDGG | -40 °C to +85 °C  | TSSOP48 | plastic thin shrink small outline package;<br>48 leads; body width 6.1 mm | <u>SOT362-1</u> |  |  |

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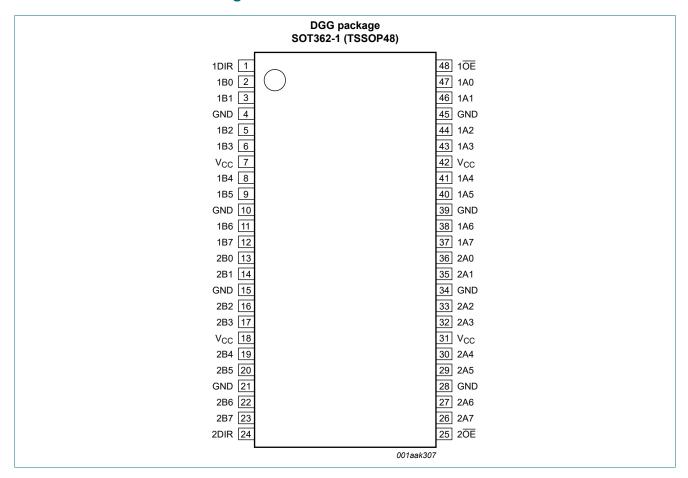
3.3 V 16-bit transceiver; 3-state

### 4. Functional diagram



### 5. Pinning information

5.1. Pinning



### 5.2. Pin description

| Table 2. Pin description               |                                |                                  |
|--|--------------------------------|----------------------------------|
| Symbol                                 | Pin                            | Description                      |
| 1DIR, 2DIR                             | 1, 24                          | direction control input          |
| 1B0, 1B1, 1B2, 1B3, 1B4, 1B5, 1B6, 1B7 | 2, 3, 5, 6, 8, 9, 11, 12       | data input/output                |
| 2B0, 2B1, 2B2, 2B3, 2B4, 2B5, 2B6, 2B7 | 13, 14, 16, 17, 19, 20, 22, 23 | data input/output                |
| GND                                    | 4, 10, 15, 21, 28, 34, 39, 45  | ground (0 V)                     |
| V <sub>CC</sub>                        | 7, 18, 31, 42                  | supply voltage                   |
| 10E, 20E                               | 48, 25                         | output enable input (active LOW) |
| 2A0, 2A1, 2A2, 2A3, 2A4, 2A5, 2A6, 2A7 | 36, 35, 33, 32, 30, 29, 27, 26 | data input/output                |
| 1A0, 1A1, 1A2, 1A3, 1A4, 1A5, 1A6, 1A7 | 47, 46, 44, 43, 41, 40, 38, 37 | data input/output                |

### 6. Functional description

#### Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

| Control |      | Input/output     |                  |  |
|---------|------|------------------|------------------|--|
| nOE     | nDIR | nAn              | nBn              |  |
| L       | L    | output nAn = nBn | input            |  |
| L       | Н    | input            | output nBn = nAn |  |
| Н       | Х    | Z                | Z                |  |

### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions                            | Min  | Max  | Unit |
|------------------|-------------------------|---------------------------------------|------|------|------|
| V <sub>CC</sub>  | supply voltage          |                                       | -0.5 | +4.6 | V    |
| VI               | input voltage           | [1]                                   | -0.5 | +7.0 | V    |
| Vo               | output voltage          | output in OFF-state or HIGH-state [1] | -0.5 | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>1</sub> < 0 V                  | -50  | -    | mA   |
| I <sub>OK</sub>  | output clamping current | V <sub>O</sub> < 0 V                  | -50  | -    | mA   |
| I <sub>O</sub>   | output current          | output in LOW-state                   | -    | 128  | mA   |
|                  |                         | output in HIGH-state                  | -64  | -    | mA   |
| T <sub>stg</sub> | storage temperature     |                                       | -65  | +150 | °C   |
| Tj               | junction temperature    | [2]                                   | -    | 150  | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +85 °C   | -    | 500  | mW   |

The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
 The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions Conditions Unit Symbol Parameter Min Max Тур V<sub>CC</sub> supply voltage 2.7 3.6 V \_ VI input voltage 0 5.5 V \_ v VIH HIGH-level input voltage 2.0 \_ \_ LOW-level input voltage V VIL \_ 0.8 \_ HIGH-level output current -32 mΑ I<sub>OH</sub> \_ -LOW-level output current none 32 mΑ I<sub>OL</sub> \_ \_ current duty cycle ≤ 50 %; 64 mΑ \_ f<sub>i</sub> ≥ 1 kHz °C ambient temperature in free-air -40 +85Tamb \_ Δt/ΔV input transition rise and fall rate outputs enabled 10 ns/V -\_

74LVTN16245B

### 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions;  $T_{amb} = -40$  °C to +85 °C; voltages are referenced to GND (ground = 0 V).

| Symbol                               | Parameter                             | Conditions  | Min                   | Тур <mark>[1]</mark> | Мах  | Unit |
|--------------------------------------|---------------------------------------|---|-----------------------|----------------------|------|------|
| V <sub>IK</sub>                      | input clamping voltage                | V <sub>CC</sub> = 2.7 V; I <sub>IK</sub> = -18 mA   | -1.2                  | -0.85                | -    | V    |
| V <sub>OH</sub>                      | HIGH-level output voltage             | $I_{OH}$ = -100 µA; V <sub>CC</sub> = 2.7 V to 3.6 V  | V <sub>CC</sub> - 0.2 | 2 V <sub>CC</sub>    | -    | V    |
|                                      |                                       | I <sub>OH</sub> = -8 mA; V <sub>CC</sub> = 2.7 V  | 2.4                   | 2.5                  | -    | V    |
|                                      |                                       | I <sub>OH</sub> = -32 mA; V <sub>CC</sub> = 3.0 V   |                       | 2.3                  | -    | V    |
| V <sub>OL</sub>                      | LOW-level output voltage              | V <sub>CC</sub> = 2.7 V   |                       |                      |      |      |
|                                      |                                       | I <sub>OL</sub> = 100 μA  |                       | 0.07                 | 0.2  | V    |
|                                      |                                       | I <sub>OL</sub> = 24 mA   | -                     | 0.3                  | 0.5  | V    |
|                                      |                                       | V <sub>CC</sub> = 3.0 V   |                       |                      |      |      |
|                                      |                                       | I <sub>OL</sub> = 16 mA   | -                     | 0.25                 | 0.4  | V    |
|                                      |                                       | I <sub>OL</sub> = 32 mA   |                       | 0.3                  | 0.5  | V    |
|                                      |                                       | I <sub>OL</sub> = 64 mA   |                       | 0.4                  | 0.55 | V    |
| I <sub>1</sub> input leakage current | input leakage current                 | control pins  |                       |                      |      |      |
|                                      |                                       | $V_{CC}$ = 3.6 V; $V_{I}$ = $V_{CC}$ or GND   | -                     | 0.1                  | ±1   | μA   |
|                                      |                                       | V <sub>CC</sub> = 0 V or 3.6 V; V <sub>I</sub> = 5.5 V  | -                     | 0.1                  | 10   | μA   |
|                                      |                                       | input/output data pins; V <sub>CC</sub> = 3.6 V   | [2]                   |                      |      |      |
|                                      |                                       | V <sub>1</sub> = 5.5 V  | -                     | 0.1                  | 20   | μA   |
|                                      |                                       | V <sub>I</sub> = V <sub>CC</sub>  | -                     | 0.5                  | 10   | μA   |
|                                      |                                       | V <sub>1</sub> = 0 V  | -5                    | -0.1                 | -    | μA   |
| I <sub>OFF</sub>                     | power-off leakage current             | $V_{CC}$ = 0 V; V <sub>I</sub> or V <sub>O</sub> = 0 V to 4.5 V   | -                     | 0.1                  | ±100 | μA   |
| I <sub>LO</sub>                      | output leakage current                | output in HIGH-state when $V_O > V_{CC}$ ;<br>$V_O = 5.5 V$ ; $V_{CC} = 3.0 V$  | -                     | 75                   | 125  | μA   |
| I <sub>O(pu/pd)</sub>                | power-up/power-down<br>output current | $V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$<br>V <sub>I</sub> = GND or V <sub>CC</sub> ; nOE = don't care   | [3] -                 | 40                   | ±100 | μA   |
| I <sub>CC</sub>                      | supply current                        | $V_{CC}$ = 3.6 V; $V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A   |                       |                      |      | _    |
|                                      |                                       | output HIGH   | -                     | 0.07                 | 0.12 | mA   |
|                                      |                                       | output LOW  | -                     | 4.0                  | 6.0  | mA   |
|                                      |                                       | outputs disabled  | [4] -                 | 0.07                 | 0.12 | mA   |
| ΔI <sub>CC</sub>                     | additional supply current             | per input pin; V <sub>CC</sub> = $3.0 \text{ V}$ to $3.6 \text{ V}$ ;<br>one input at V <sub>CC</sub> - $0.6 \text{ V}$ ,<br>other inputs at V <sub>CC</sub> or GND | [5] -                 | 0.1                  | 0.2  | mA   |
| CI                                   | input capacitance                     | pins nDIR and n $\overline{OE}$ , V <sub>O</sub> = 0 V or 3.0 V   | -                     | 3                    | -    | pF   |
| C <sub>io(off)</sub>                 | off-state input/output<br>capacitance | pins nAn and nBn, outputs disabled; $V_O$ = GND or $V_{CC}$   | -                     | 9                    | -    | pF   |

[1] Typical values are measured at  $V_{CC}$  = 3.3 V and at  $T_{amb}$  = 25 °C.

[2] Unused pins at  $V_{CC}$  or GND.

[3] This parameter is valid for any  $V_{CC}$  between 0 V and 1.2 V with a transition time of up to 10 ms.

From  $V_{CC} = 1.2$  V to  $V_{CC} = 3.3$  V ± 0.3 V a transition time of 100 µs is permitted. This parameter is valid for  $T_{amb} = 25$  °C only. [4]  $I_{CC}$  is measured with outputs pulled to  $V_{CC}$  or GND.

[5] This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND.

### **10.** Dynamic characteristics

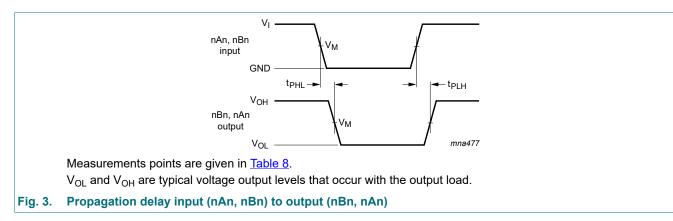
#### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); T<sub>amb</sub> = -40 °C to +85 °C; for test circuit see Fig. 5.

| Symbol           | Parameter                          | Conditions                           | Min | Тур [1] | Max | Unit |
|------------------|------------------------------------|--------------------------------------|-----|---------|-----|------|
| t <sub>PLH</sub> | LOW to HIGH                        | nAn to nBn or nBn to nAn; see Fig. 3 |     |         |     |      |
|                  | propagation delay                  | V <sub>CC</sub> = 2.7 V              | -   | -       | 3.5 | ns   |
|                  |                                    | V <sub>CC</sub> = 3.0 V to 3.6 V     | 1.0 | 1.9     | 3.3 | ns   |
| t <sub>PHL</sub> | t <sub>PHL</sub> HIGH to LOW       | nAn to nBn or nBn to nAn; see Fig. 3 |     |         |     |      |
|                  | propagation delay                  | V <sub>CC</sub> = 2.7 V              | -   | -       | 3.5 | ns   |
|                  |                                    | V <sub>CC</sub> = 3.0 V to 3.6 V     | 1.0 | 1.7     | 3.3 | ns   |
| t <sub>PZH</sub> | t <sub>PZH</sub> OFF-state to HIGH | nOE to nAn or nBn; see Fig. 4        |     |         |     |      |
|                  | propagation delay                  | V <sub>CC</sub> = 2.7 V              | -   | -       | 5.3 | ns   |
|                  |                                    | V <sub>CC</sub> = 3.0 V to 3.6 V     | 1.0 | 2.8     | 4.5 | ns   |
| t <sub>PZL</sub> | PZL OFF-state to LOW               | nOE to nAn or nBn; see Fig. 4        |     |         |     |      |
|                  | propagation delay                  | V <sub>CC</sub> = 2.7 V              | -   | -       | 5.1 | ns   |
|                  |                                    | V <sub>CC</sub> = 3.0 V to 3.6 V     | 1.0 | 2.8     | 4.1 | ns   |
| t <sub>PHZ</sub> | HIGH to OFF-state                  | nOE to nAn or nBn; see Fig. 4        |     |         |     |      |
|                  | propagation delay                  | V <sub>CC</sub> = 2.7 V              | -   | -       | 5.7 | ns   |
|                  |                                    | V <sub>CC</sub> = 3.0 V to 3.6 V     | 1.5 | 3.2     | 5.1 | ns   |
| t <sub>PLZ</sub> | LOW to OFF-state                   | nOE to nAn or nBn; see <u>Fig. 4</u> |     |         |     |      |
|                  | propagation delay                  | V <sub>CC</sub> = 2.7 V              | -   | -       | 4.6 | ns   |
|                  |                                    | V <sub>CC</sub> = 3.0 V to 3.6 V     | 1.5 | 3.0     | 4.6 | ns   |

[1] Typical values are measured at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C.

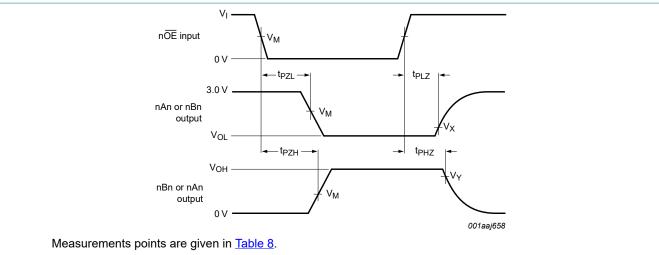
### 10.1. Waveforms and test circuit



6/12

### 74LVTN16245B

#### 3.3 V 16-bit transceiver; 3-state



 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

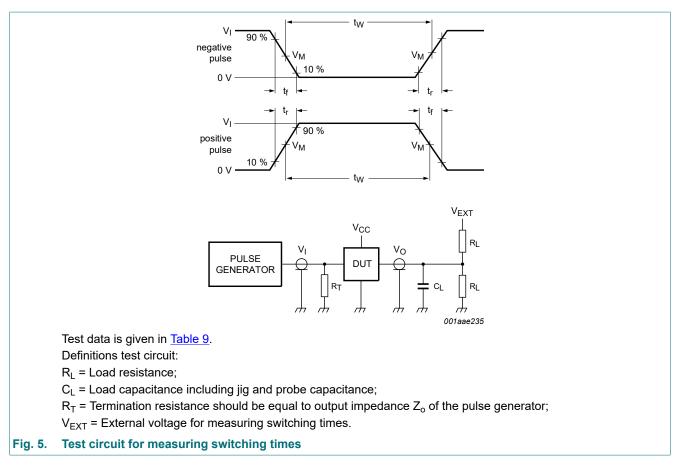
#### Fig. 4. Enable and disable times

#### Table 8. Measurement points

| Input          | Output         |                         |                         |
|----------------|----------------|-------------------------|-------------------------|
| V <sub>M</sub> | V <sub>M</sub> | V <sub>X</sub>          | V <sub>Y</sub>          |
| 1.5 V          | 1.5 V          | V <sub>OL</sub> + 0.3 V | V <sub>OH</sub> - 0.3 V |

### 74LVTN16245B

#### 3.3 V 16-bit transceiver; 3-state

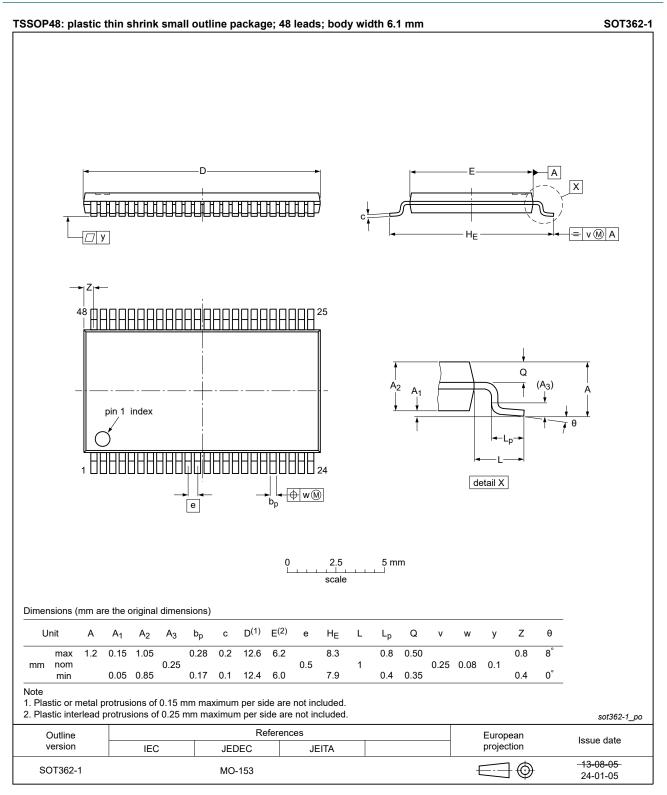


#### Table 9. Test data

| Input |                |        | Load V <sub>EXT</sub>           |       |       |                                     |                                     |                                     |
|-------|----------------|--------|---------------------------------|-------|-------|-------------------------------------|-------------------------------------|-------------------------------------|
| VI    | f <sub>i</sub> | tw     | t <sub>r</sub> , t <sub>f</sub> | CL    | RL    | t <sub>PHZ</sub> , t <sub>PZH</sub> | t <sub>PLZ</sub> , t <sub>PZL</sub> | t <sub>PLH</sub> , t <sub>PHL</sub> |
| 2.7 V | ≤ 10 MHz       | 500 ns | ≤ 2.5 ns                        | 50 pF | 500 Ω | GND                                 | 6 V                                 | open                                |

#### 3.3 V 16-bit transceiver; 3-state

### **11. Package outline**



#### Fig. 6. Package outline SOT362-1 (TSSOP48)

### 12. Abbreviations

| Table 10. Abbreviati | ons   |
|----------------------|---|
| Acronym              | Description                                     |
| ANSI                 | American National Standards Institute           |
| BiCMOS               | Bipolar Complementary Metal Oxide Semiconductor |
| CDM                  | Charged Device Model                            |
| DUT                  | Device Under Test                               |
| ESD                  | ElectroStatic Discharge                         |
| ESDA                 | ElectroStatic Discharge Association             |
| HBM                  | Human Body Model                                |
| JEDEC                | Joint Electron Device Engineering Council       |
| TTL                  | Transistor-Transistor Logic                     |

### 13. Revision history

| Document ID                        | Release date              | Data sheet status   | Change notice                          | Supersedes                              |
|------------------------------------|---------------------------|---|--|---|
| 74LVTN16245B v.8                   | 20240708                  | Product data sheet  | -                                      | 74LVTN16245B v.7                        |
| Modifications:                     | Section 2: E              | SD specification updated  | according to the lat                   | est JEDEC standard.                     |
| 74LVTN16245B v.7                   | 20240212                  | Product data sheet  | -                                      | 74LVTN16245B v.6                        |
| Modifications:                     |                           | Derating values for P <sub>tot</sub> tota<br>ated package outline draw                |  |   |
| 74LVTN16245B v.6                   | 20181030                  | Product data sheet  | -                                      | 74LVTN16245B v.5                        |
|                                    | Type number               | have been adapted to the<br>ers 74LVTN16245BBX (S0<br>tline drawing <u>SOT362-1</u> u | OT1134-2) removed                      |   |
| 74LVTN16245B v.5                   | 20120405                  |   |  |   |
|                                    |                           | Product data sheet  | -                                      | 74LVTN16245B v.4                        |
| Modifications:                     | For type null             | Product data sheet<br>mber 74LVTN16245BBX t   | -<br>he SOT code has c                 |   |
| Modifications:<br>74LVTN16245B v.4 | • For type nu<br>20111122 |   | he SOT code has c                      |   |
|                                    |                           | mber 74LVTN16245BBX t   | -<br>he SOT code has c<br>-            | hanged to SOT1134-2                     |
| 74LVTN16245B v.4                   | 20111122                  | mber 74LVTN16245BBX t   | -<br>he SOT code has c<br>-<br>-       | hanged to SOT1134-2                     |
| 74LVTN16245B v.4<br>Modifications: | 20111122<br>• Legal pages | mber 74LVTN16245BBX t<br>Product data sheet<br>s updated.                             | -<br>the SOT code has c<br>-<br>-<br>- | hanged to SOT1134-2<br>74LVTN16245B v.3 |

3.3 V 16-bit transceiver; 3-state

## 14. Legal information

#### Data sheet status

| Document status<br>[1][2]         | Product<br>status [3] | Definition  |
|-----------------------------------|-----------------------|---|
| Objective [short]<br>data sheet   | Development           | This document contains data from<br>the objective specification for<br>product development. |
| Preliminary [short]<br>data sheet | Qualification         | This document contains data from the preliminary specification.                             |
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 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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### Contents

| 1. General description              | 1  |
|-------------------------------------|----|
| 2. Features and benefits            | 1  |
| 3. Ordering information             | 1  |
| 4. Functional diagram               | 2  |
| 5. Pinning information              | 3  |
| 5.1. Pinning                        | 3  |
| 5.2. Pin description                | 3  |
| 6. Functional description           | 4  |
| 7. Limiting values                  | 4  |
| 8. Recommended operating conditions | 4  |
| 9. Static characteristics           | 5  |
| 10. Dynamic characteristics         | 6  |
| 10.1. Waveforms and test circuit    | 6  |
| 11. Package outline                 | 9  |
| 12. Abbreviations                   | 10 |
| 13. Revision history                | 10 |
| 14. Legal information               | 11 |
|                                     |    |

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